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RoHS

HALOGEN

FREE

GREEN



Vishay Semiconductors

High Speed Infrared Emitting Diode, 940 nm, Surface Emitter Technology



DESCRIPTION

As part of the <u>SurfLight^{IM}</u> portfolio, the VSLY5940 is an infrared, 940 nm emitting diode based on GaAlAs surface emitter chip technology with extreme high radiant intensity, high optical power and high speed, molded in a clear, untinted plastic package, with a parabolic lens.

FEATURES

Package type: leadedPackage form: T-1¾

Dimensions (in mm): Ø 5

Leads with stand-off

Peak wavelength: λ_p = 940 nm

· High reliability

High radiant power

• High radiant intensity

• Narrow angle of half intensity: $\varphi = \pm 3^{\circ}$

• Suitable for high pulse current operation

• Good spectral matching with CMOS cameras

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Infrared radiation source for operation with CMOS cameras
- · High speed IR data transmission
- Smoke-automatic fire detectors
- IR Flash

PRODUCT SUMMARY				
COMPONENT	I _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)
VSLY5940	600	± 3	940	10

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSLY5940	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		
VSLY5940-CS21	Reel	MOQ: 5000 pcs, 1000 pcs/bulk	T-1¾		

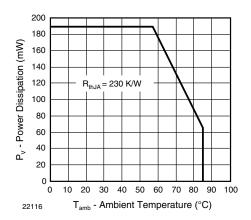
Note

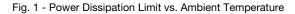
MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V_{R}	5	V	
Forward current		I _F	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	1	Α	
Power dissipation		P _V	190	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	-40 to +85	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Soldering temperature	$t \le 5$ s, 2 mm from case	T _{sd}	260	°C	
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	230	K/W	



Vishay Semiconductors





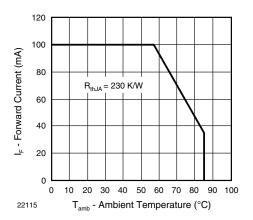


Fig. 2 - Forward Current Limit vs. Ambient Temperature

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F		1.65	1.9	V
	I _F = 1 A, t _p = 100 μs	V _F		2.9		V
Temperature coefficient of V _F	I _F = 1 mA	TK _{VF}		-1.45		mV/K
	I _F = 10 mA	TK _{VF}		-1.25		mV/K
Reverse current		I _R	not designed for reverse operation		μΑ	
Junction capacitance	$V_R = 0 \text{ V, } f = 1 \text{ MHz, } E = 0$	Cj		125		pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	I _e	300	600	900	mW/sr
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	I _e		5100		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe		55		mW
Temperature coefficient of φ _e	I _F = 100 mA	TKφ _e		-0.35		%/K
Angle of half intensity		φ		± 3		deg
Peak wavelength	I _F = 100 mA	λρ	920	940	960	nm
Spectral bandwidth	I _F = 100 mA	Δλ		35		nm
Temperature coefficient of λ_p	I _F = 100 mA	TKλ _p		0.25		nm/K
Rise time	I _F = 100 mA	t _r		10		ns
Fall time	I _F = 100 mA	t _f		10		ns

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

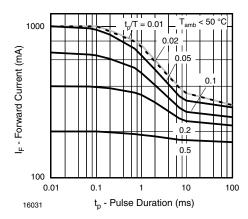


Fig. 3 - Pulse Forward Current vs. Pulse Duration

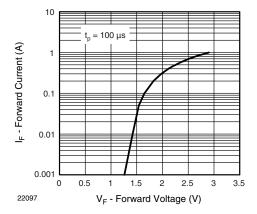


Fig. 4 - Forward Current vs. Forward Voltage

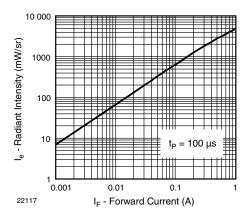


Fig. 5 - Radiant Intensity vs. Forward Current

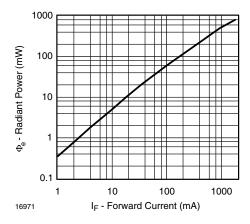


Fig. 6 - Radiant Power vs. Forward Current

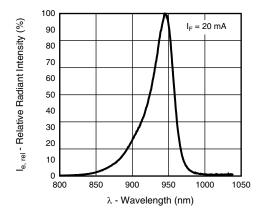


Fig. 7 - Relative Radiant Power vs. Wavelength

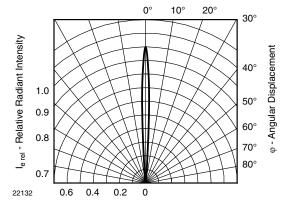
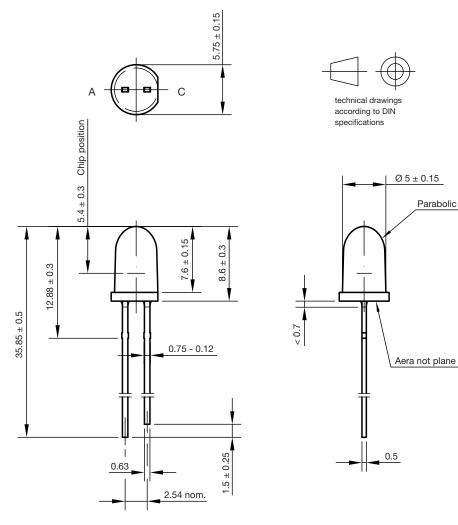


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

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Parabolic lens

PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.544-5385.01-4

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20531

Not indicated tolerances \pm 0.1



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